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Please use the following format to cite material from this book:

ISSN: 0277-786X
ISBN: 9780819492012

Published by
SPIE
P.O. Box 10, Bellingham, Washington 98227-0010 USA
Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445
SPIE.org

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